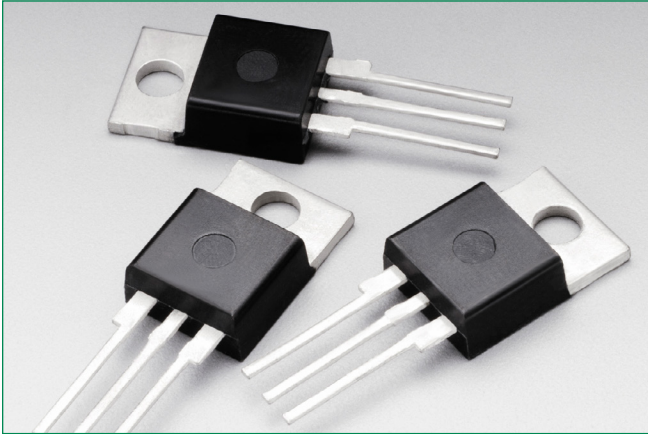


# 2N6344A, 2N6348A, 2N6349A

Surface Mount – 600-800V



## Description

The 2N634xA is designed primarily for full-wave AC control applications, such as light dimmers, motor controls, heating controls and power supplies; or wherever full-wave silicon gate controlled solid-state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied anode voltage with positive or negative gate triggering.

## Features

- Blocking Voltage to 800 V
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Gate Triggering Guaranteed in all Four Quadrants
- For 400 Hz Operation, Consult Factory
- 8.0 A Devices Available as 2N6344 thru 2N6349
- Pb-Free Package is Available

## Additional Information



Resources

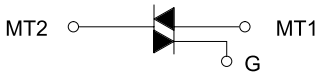


Accessories

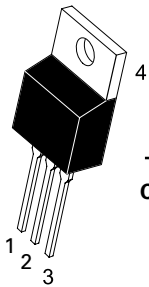


Samples

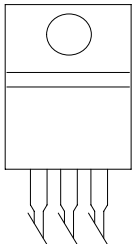
## Functional Diagram



## Pin Out



TO-220AB  
CASE 221A  
STYLE 4



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### Maximum Ratings and Thermal Characteristics (T<sub>J</sub> = 25°C unless otherwise noted)

Rating		Symbol	Value	Unit
*Peak Repetitive Off-State Voltage (Note 1) (T <sub>J</sub> = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open)	2N6344A, 2N6348A	V <sub>DRM'</sub>	600	V
	2N6349A	V <sub>RRM</sub>	800	
*On-State RMS Current (Full Cycle Sine Wave 50 to 60 Hz)	(T <sub>C</sub> = +80°C)	I <sub>T (RMS)</sub>	12	A
	(T <sub>C</sub> = +90°C)		6.0	
*Peak Non-Repetitive Surge Current (One Full Cycle, Sine Wave 60 Hz, T <sub>C</sub> = +80°C) Preceded and followed by rated current		I <sub>TSM</sub>	100	A
Circuit Fusing Considerations (t = 8.3 ms)		I <sup>2</sup> t	59	A <sup>2</sup> s
*Peak Gate Power (T <sub>C</sub> = +80°C, Pulse Width = 2 μs)		P <sub>GM</sub>	20	W
*Average Gate Power (T <sub>C</sub> = +80°C, t = 8.3 ms)		P <sub>G(AV)</sub>	0.5	W
*Peak Gate Current (T <sub>C</sub> = +80°C, Pulse Width = 2.0 μs)		I <sub>GM</sub>	2.0	A
*Peak Gate Voltage (T <sub>C</sub> = +80°C, Pulse Width = 2.0 μs)		V <sub>GM</sub>	±10	V
*Operating Junction Temperature Range		T <sub>J</sub>	-40 to +125	°C
*Storage Temperature Range		T <sub>stg</sub>	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\* Indicates JEDEC Registered Data.

1. V<sub>DRM'</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

### Thermal Characteristics

Rating	Symbol	Value	Unit
† Thermal Resistance, Junction to Case	R <sub>θJC</sub>	2.0	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	T <sub>L</sub>	260	°C

† Indicates JEDEC Registered Data.

### Electrical Characteristics - OFF (T<sub>C</sub> = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Typ	Max	Unit
*Peak Repetitive Blocking Current (V <sub>D</sub> = V <sub>DRM'</sub> = V <sub>RRM'</sub> ; Gate Open)	T <sub>J</sub> = 25°C	I <sub>DRM'</sub>	-	-	10	μA
	T <sub>J</sub> = 100°C	I <sub>RRM</sub>	-	-	2.0	mA

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### Electrical Characteristics - ON (TC = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit	
†Peak On-State Voltage ( $I_{TM} = \pm 17$ A Peak; Pulse Width = 1 to 2 ms, Duty Cycle $\leq 2\%$ )	$V_{TM}$	-	1.3	175	V	
<b>Gate Trigger Current (Continuous dc) (<math>V_D = 12</math> Vdc, <math>R_L = 100 \Omega</math>)</b>						
Quadrant I: MT2(+), G(+)	All	-	6.0	50	mA	
Quadrant II: MT2(+), G(-)	2N6348A & 2N6349A	-	6.0	75		
Quadrant III: MT2(-), G(-)	All	-	10	50		
Quadrant IV: MT2(-), G(+)	2N6348A & 2N6349A	-	25	75		
†MT2(+), G(+); MT2(-), G(-)	$T_C = -40^\circ\text{C}$	-	-	100		
†MT2(+), G(-); MT2(-), G(+)	$T_C = -40^\circ\text{C}$	-	-	125		
<b>Gate Trigger Voltage (Continuous dc) (<math>V_D = 12</math> Vdc, <math>R_L = 100 \Omega</math>)</b>						
Quadrant I: MT2(+), G(+)	Both	-	0.9	2.0	V	
Quadrant II: MT2(+), G(-)	2N6348A & 2N6349A	-	0.9	2.5		
Quadrant III: MT2(-), G(-)	Both	-	1.1	2.0		
Quadrant IV: MT2(-), G(+)	2N6348A & 2N6349A	-	1.4	2.5		
†MT2(+), G(+); MT2(-), G(-)	$T_C = -40^\circ\text{C}$	-	-	2.5		
†MT2(+), G(-); MT2(-), G(+)	$T_C = -40^\circ\text{C}$	-	-	3.0		
Gate Non-Trigger Voltage (Continuous dc) ( $V_D = \text{Rated } V_{DRM}$ , $R_L = 10 \text{ k } \Omega$ , $T_J = 100^\circ\text{C}$ ) †MT2(+), G(+); MT2(-), G(-); MT2(+), G(-); MT2(-), G(-)	$V_{GD}$	.02	-	-		
Holding Current ( $V_D = 12$ Vdc, Gate Open) Initiating Current = 200 mA	$I_H$	$T_C = 25^\circ\text{C}$	-	6.0	40	mA
		$T_C = -40^\circ\text{C}$	-	-	75	
†Turn-On Time ( $V_D = \text{Rated } V_{DRM}$ , $I_{TM} = 11$ A, $I_{GT} = 120$ mA, Rise Time = 0.1 $\mu\text{s}$ , Pulse Width = 2 $\mu\text{s}$ )	$t_{gt}$	-	10	15	$\mu\text{s}$	

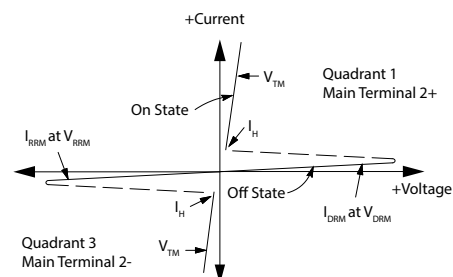
† Indicates JEDEC Registered Data.

### Dynamic Characteristics

Characteristic	Symbol	Min	Typ	Max	Unit
Critical Rate of Rise of Commutation Voltage ( $V_D = \text{Rated } V_{DRM}$ , $I_{TM} = 17$ A, Commutating $di/dt = 6.1$ A/ms, Gate Unenergized, $T_C = 80^\circ\text{C}$ )	$dv/dt(c)$	-	5.0	-	V/ $\mu\text{s}$

### Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
$I_H$	Holding Current



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## Ratings and Characteristic Curves

Figure 1. RMS Current Derating

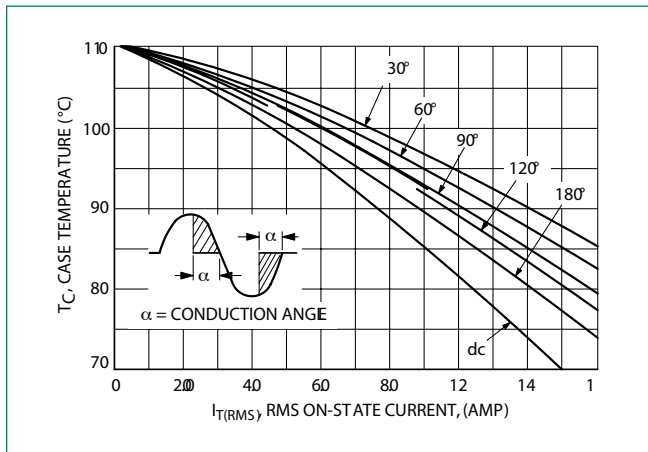


Figure 2. On-State Power Dissipation

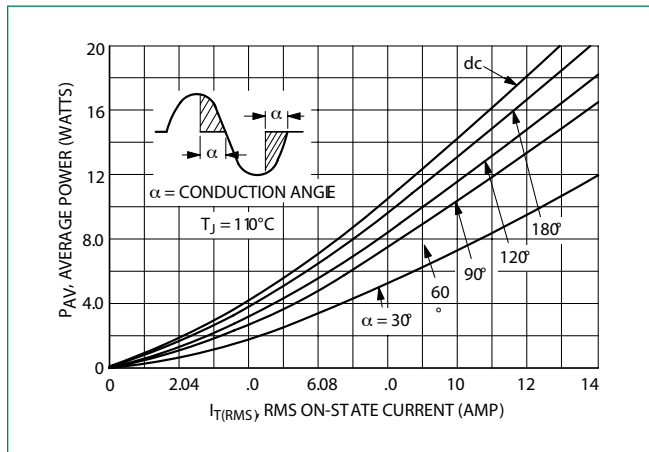


Figure 3. Typical Gate Trigger Voltage

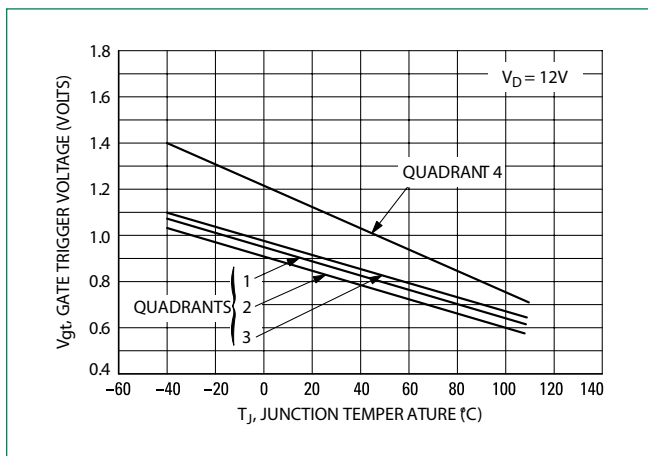
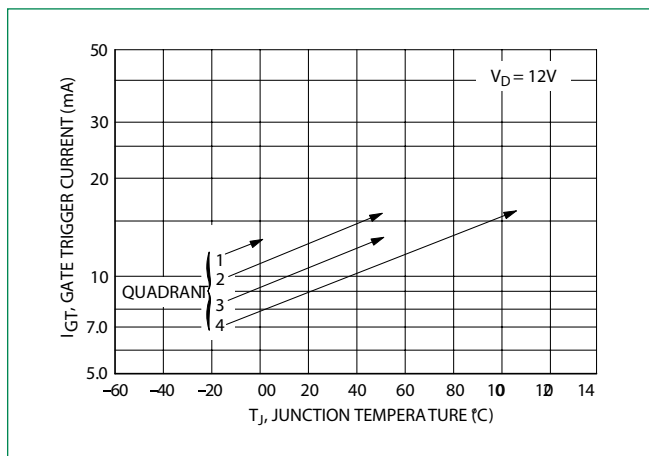


Figure 4. Typical Gate Trigger Current



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Figure 7. Maximum On-State Characteristics

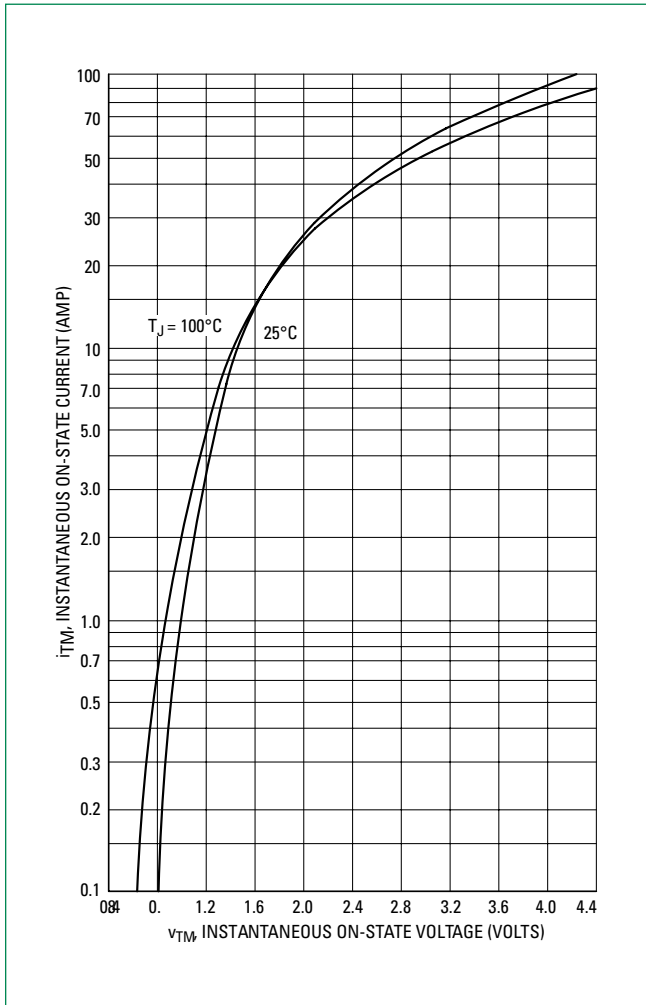


Figure 8. Typical Holding Current

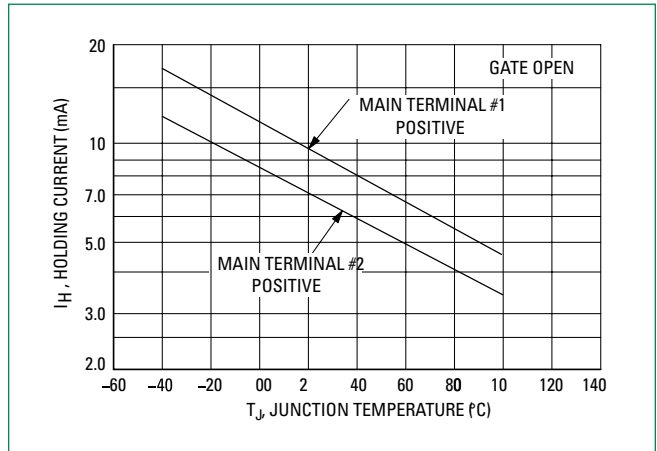


Figure 9. Maximum Allowable Surge Current

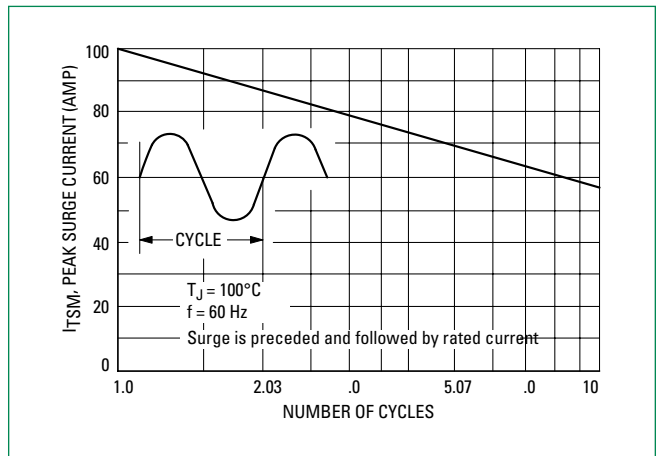


Figure 10. Typical Thermal Response

